

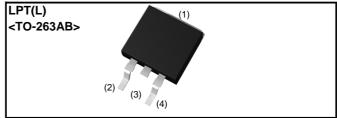
V _R	650V
١ _F	15A
Q _C	23nC

Features

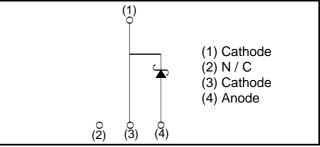
Construction

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

Outline



Inner circuit



Packaging specifications

	Packaging	Embossed tape
	Reel size (mm)	330
Tupo	Tape width (mm)	24
Туре	Basic ordering unit (pcs)	1,000
	Taping code	TLL
	Marking	SCS215AJ

• Absolute maximum ratings $(T_i = 25^{\circ}C)$

Silicon carbide epitaxial planer Shottoky Diode

5 ()				
Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V _{RM}	650	V	
Reverse voltage (DC)	V _R	650	V	
Continuous forward current	١ _F	15* ¹	А	
	I _{FSM}	55* ²	А	
Surge no repetitive forward current		200* ³	А	
		43* ⁴	А	
Repetitive peak forward current	I _{FRM}	56* ⁵	А	
Total power dissipation	P _D	100* ⁶	W	
Junction temperature	Tj	175	°C	
Range of storage temperature	T _{stg}	-55 to +175	°C	

*1 T_c =120°C *2 PW=8.3ms sinusoidal, T_j =25°C

*3 PW=10 μ s square, T_j=25°C *4 PW=8.3ms sinusoidal, T_j=150°C

*5 T_c =100°C, T_j =150°C, Duty cycle=10% *6 T_c =25°C

•Electrical characteristics ($T_j = 25^{\circ}C$)

Parameter	Symbol	Conditions	Values			L locit
Parameter		Conditions	Min.	Тур.	Max.	Unit
DC blocking voltage	V _{DC}	I _R =0.3mA	600	-	-	V
Forward voltage	V _F	I _F =15A,T _j =25°C	-	1.35	1.55	V
		I _F =15A,T _j =150°C	-	1.55	-	V
		I _F =15A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	3	300	μA
		V _R =600V,T _j =150°C	-	45	-	μA
		V _R =600V,T _j =175°C	-	105	-	μA
Total capacitance	С	V _R =1V,f=1MHz	-	550	-	pF
		V _R =600V,f=1MHz	-	56	-	pF
Total capacitive charge	Q _c	V _R =400V,di/dt=350A/μs	-	23	-	nC
Switching time	t _c	V _R =400V,di/dt=350A/μs	-	18	-	ns

•Thermal characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Thermal resistance	R _{th(j-c)}	-	-	1.2	1.5	°C/W

•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

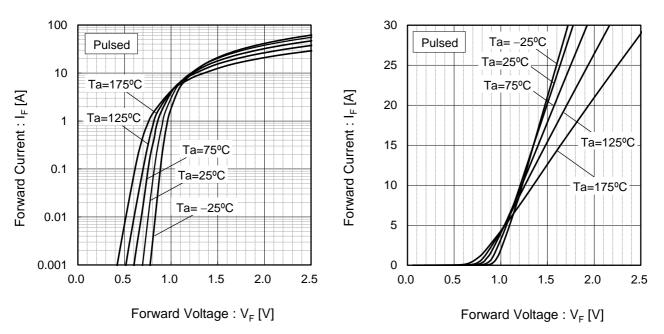
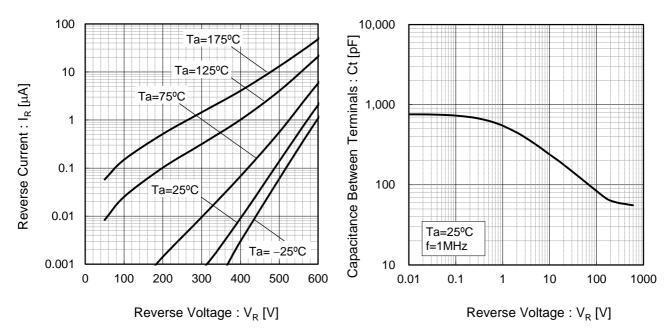


Fig.2 V_F - I_F Characteristics

Fig.3 V_R - I_R Characteristics

Fig.4 V_R -Ct Characteristics



•Electrical characteristic curves

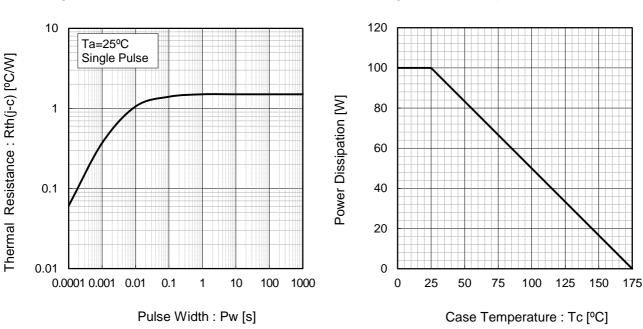


Fig.5 Thermal Resistance vs. Pulse Width

Fig.7 Ip-Tc Derating Curve

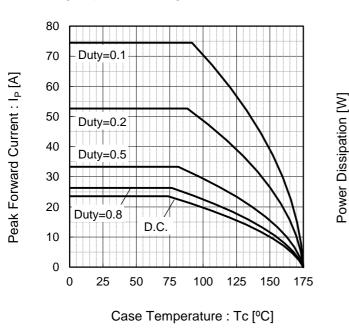
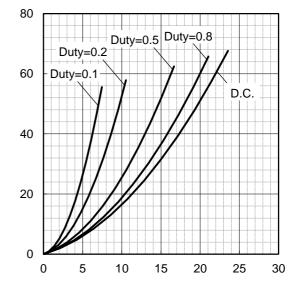


Fig.8 Io-Pf Characteristics

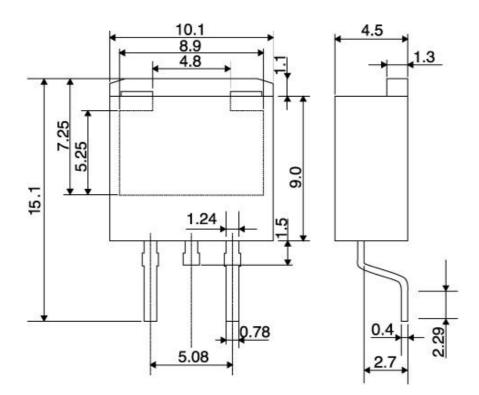
Fig.6 Power Dissipation



Average Rectified Forward Current : Io [A]

•Dimensions (Unit : mm)

LPT(L)



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